

ProductID 308-FG-02 series

Bare Die (Flip chip form, Au Pad)

Typical Optical-Electrical Characteristics

 $(I_{F}=100 \text{mA}, T_{a}=25^{\circ}\text{C})$

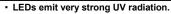
ltem	Symbol	Unit	308-FG-02-C		
			Min	Тур	Max
Peak Wavelength	λ _p	nm	303	308	313
Radiant Flux	Po	mW	-	24	-
Full Width at Half Maximum	⊿λ	nm	-	15	-
Forward Voltage	V _F	V	-	5.4	-

(*)Peak Wavelength Measurement tolerance is ±3nm.

(**)Radiant Flux Measurement tolerance is ±10%.

Specification and dimension are subject to change for improvement without notice.

Product ID, Physical dimensions and Sapmle photo 308-FG-02-C 308-FG-02-S0A Cathode 780 -1500-Unit : µm 13,00 780 586 750 ÷ 750 Anode Anode 160 246 Cathode 200 Au Pad thickness: 3µm 310 540 310 2 ΟÓ WARNING



Do not look at the LED light with the naked eye or irradiate the skin.

- UV radiation can harm your eyes and skin.
- To prevent UV radiation exposure, wear protective eyewear and protective equipment.
- If LEDs are embedded in devices, please indicate warning labels against the UV light LED used.
- Keep out of reach of children.

DOWA Electronics Materials Co., Ltd.

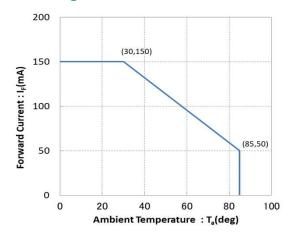


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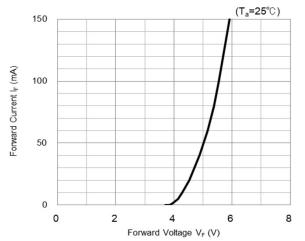
Absolute Maximum Ratings

ltem	Symbol	Unit	Value
Forward Current	I _F	mA	150
Junction Temperature	TJ	°C	90
Operating Temperature	T _{OPR}	°C	-30 ~ +85
Storage Temperature	T _{STR}	°C	-40 \sim +85 (No condensation)

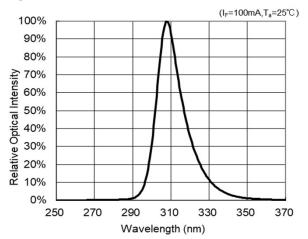
Derating Curve



Forward Voltage vs Forward Current



Spectrum



Forward Current vs Radiant Flux

